

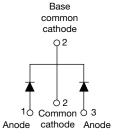
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Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 8 A

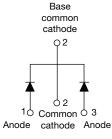
VS-16CTQ...SPbF











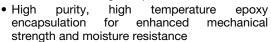
D²PAK

TO-262

PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	2 x 8 A
V_{R}	60 V to 100 V
V _F at I _F	0.58 V
I _{RM}	7 mA at 125 °C
T _J max.	175 °C
Diode variation	Common cathode
E _{AS}	7.5 mJ

FEATURES

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop





ROHS COMPLIANT HALOGEN

FREE

• High frequency operation

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	16	A				
V _{RRM}		60 to 100	V				
I _{FSM}	$t_p = 5 \mu s sine$	850	A				
V _F	8 Apk, T _J = 125 °C (per leg)	0.58	V				
T _J	Range	-55 to 175	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-16CTQ060SPbF VS-16CTQ060-1PbF	VS-16CTQ080SPbF VS-16CTQ080-1PbF	VS-16CTQ100SPbF VS-16CTQ100-1PbF	UNITS	
Maximum DC reverse voltage	V_R	60	80	100	V	
Maximum working peak reverse voltage	V_{RWM}	00	00	100	V	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average	per leg				8		
forward current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T _C = 148 °C, rectangular waveform		16	А	
Maximum peak one cycle			5 μs sine or 3 μs rect. pulse	Following any rated load	850		
non-repetitive surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	275	Α	
Non-repetitive avalanche ene	ergy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.50 \text{A}, L = 60 ^{\circ}$	mH	7.50	mJ	
Repetitive avalanche current	Repetitive avalanche current per leg		Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.50	А	



VS-16CTQ...SPbF, VS-16CTQ...-1PbF Series

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		8 A	T _{.1} = 25 °C	0.72		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	16 A	1j=25 C	0.88	V	
See fig. 1	V _{FM} (1)	8 A	T 105 °C	0.58		
		16 A	T _J = 125 °C	0.69		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.55	mA	
See fig. 2		T _J = 125 °C		7.0		
Threshold voltage	V _{F(TO)}	T T manyimum		0.415	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		11.07	mΩ	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	ge 100 kHz to 1 MHz), 25 °C	500	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 n	nm from package body	8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 175	°C	
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package		D	DC operation	3.25		
		R _{thJC}		1.63	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque –	maximum			12 (10)	(lbf · in)	
Mayling davide			Case style D ² PAK	16CT	QS	
Marking device			Case style TO-262	16CT	Q1	

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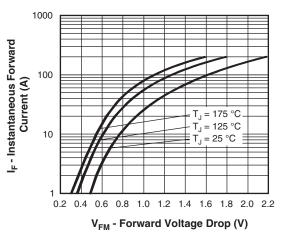


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

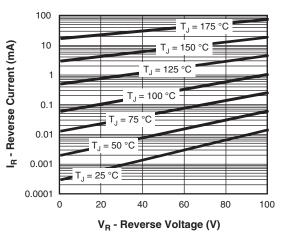


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

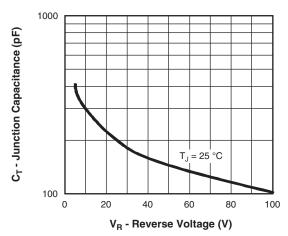


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

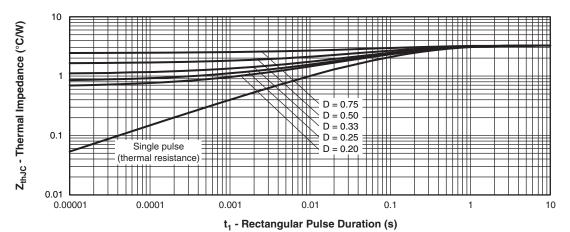


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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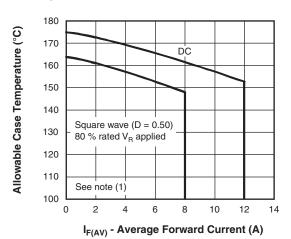


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

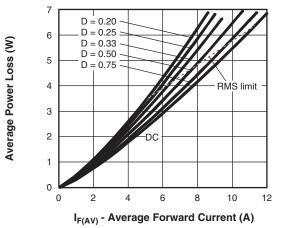


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

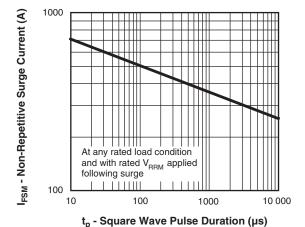


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

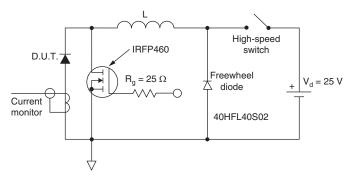


Fig. 8 - Unclamped Inductive Test Circuit

Note

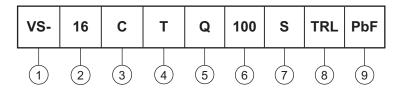
[1] Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse$ power loss $= V_{R1} \times I_{R}$ (1 - D); I_{R} at $V_{R1} = 80$ % rated V_{R} applied

VS-16CTQ...SPbF, VS-16CTQ...-1PbF Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product suffix

Current rating (16 A)

3 Circuit configuration: C = Common cathode

T = TO-220

Schottky "Q" series

060 = 60 V V = 080Voltage ratings

• $S = D^2PAK$

100 = 100 V

• -1 = TO-262

8 • None = Tube (50 pieces)

• TRL = Tape and reel (left oriented - for D²PAK only)

• TRR = Tape and reel (right oriented - for D²PAK only)

9 PbF = Lead (Pb)-free

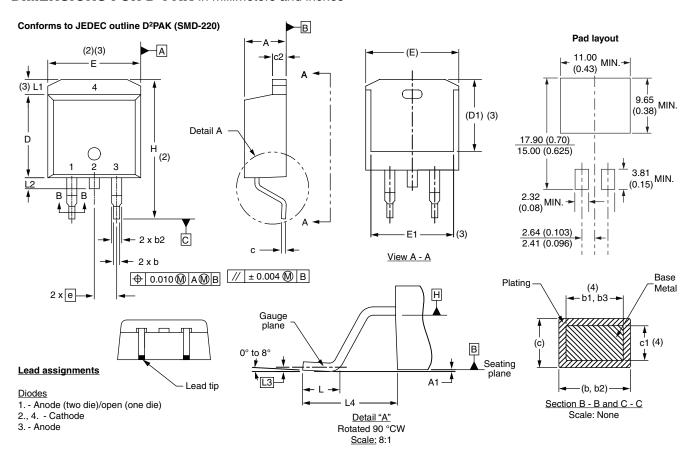
LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95014						
Part marking information	www.vishay.com/doc?95008					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?95279					



Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches



0)////	MILLIM	IETERS	INC	NOTEO	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

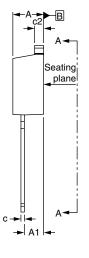
(7) Outline conforms to JEDEC outline TO-263AB

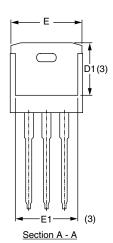
Vishay High Power Products

D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches





⊕ 0.010**⋒**|A**⋒**|B

Lead assignments

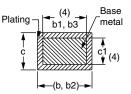


<u>Diodes</u>

-3 x b2 --3 x b

> 1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIMETERS		INC	INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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SBAT54CWT1G SBM30-03-TR-E SK32A-LTP SK33A-TP SK34A-TP SK34B-TP SMD1200PL-TP ACDBN160-HF SS3003CH-TL-E
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